To our customers,

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

Phase-out/Discontinued

μPA2503

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μPA2503, which has a heat spreader, is N-channel MOS Field Effect Transistor designed for power management applications of notebook computers.

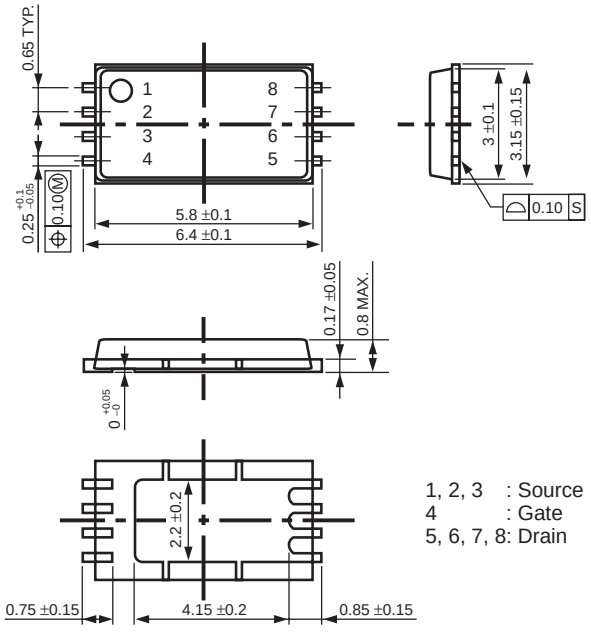
FEATURES

- μPA2503 has a thin surface mount package with a heat spreader. The land size is same as 8-pin TSSOP.
- Low on-state resistance
  $R_{DS(on)1}$ = 9.5 mΩ MAX. (V_{GS} = 10.0 V, I_D = 8.0 A)
  $R_{DS(on)2}$ = 15.1 mΩ MAX. (V_{GS} = 4.5 V, I_D = 8.0 A)
- Low C_{iss}: 1200 pF TYP. (V_{DS} = 10.0 V, V_{GS} = 0 V)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA2503TM	8PIN HWSON

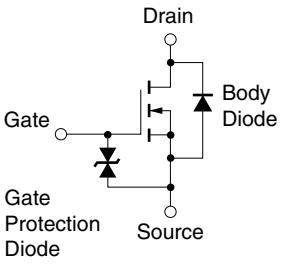
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	30.0	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±20.0	V
Drain Current (DC) Note1	$I_{D(DC)}$	±16.0	A
Drain Current (pulse) Note2	$I_{D(pulse)}$	±64.0	A
Total Power Dissipation Note1	P_T	2.7	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C
Single Avalanche Current Note3	I_{AS}	16.0	A
Single Avalanche Energy Note3	E_{AS}	25.6	mJ

EQUIVALENT CIRCUIT



Notes 1. Mounted on FR-4 board of 25 cm^2 x 1.6 mm, PW ≤ 10 sec

2. PW ≤ 10 μs, Duty Cycle ≤ 1%

3. Starting T_{ch} = 25°C, V_{DD} = 30 V, R_G = 25 Ω, V_{GS} = 20.0 → 0 V

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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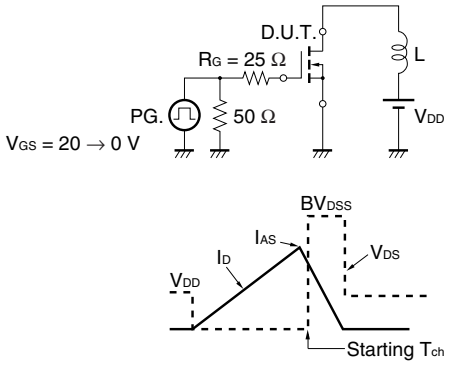
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

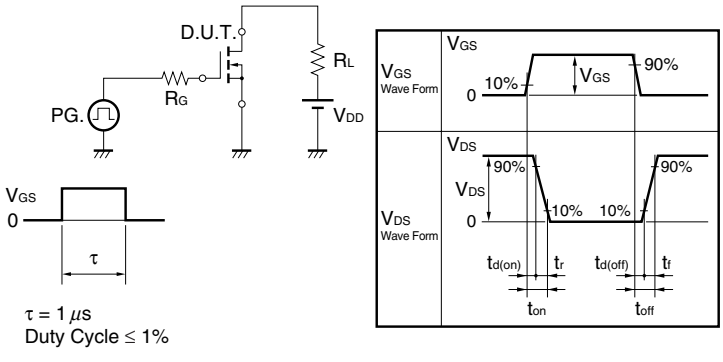
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 30.0 V, V_{GS} = 0 V			1.0	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ±18.0 V, V_{DS} = 0 V			±10.0	μA
Gate Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10.0 V, I_D = 1.0 mA	1.5		2.5	V
Forward Transfer Admittance **Note**	$\|y_{fs}\|$	V_{DS} = 10.0 V, I_D = 8.0 A	5			S
Drain to Source On-state Resistance **Note**	$R_{DS(on)1}$	V_{GS} = 10.0 V, I_D = 8.0 A		7.5	9.5	mΩ
	$R_{DS(on)2}$	V_{GS} = 4.5 V, I_D = 8.0 A		11.0	15.1	mΩ
Input Capacitance	C_{iss}	V_{DS} = 10.0 V		1200		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		320		pF
Reverse Transfer Capacitance	C_{rss}	f = 1.0 MHz		190		pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = 15.0 V, I_D = 8.0 A		12		ns
Rise Time	t_r	V_{GS} = 10.0 V		17		ns
Turn-off Delay Time	$t_{d(off)}$	R_G = 10 Ω		52		ns
Fall Time	t_f			15		ns
Total Gate Charge	Q_G	V_{DD} = 15.0 V		15		nC
Gate to Source Charge	Q_{GS}	V_{GS} = 5.0 V		4		nC
Gate to Drain Charge	Q_{GD}	I_D = 16.0 A		7		nC
Body Diode Forward Voltage **Note**	$V_{F(S-D)}$	I_F = 16.0 A, V_{GS} = 0 V		0.84		V
Reverse Recovery Time	t_{rr}	I_F = 16.0 A, V_{GS} = 0 V		28		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μs		18		nC

Note Pulsed: PW ≤ 350 μs, Duty Cycle ≤ 2%

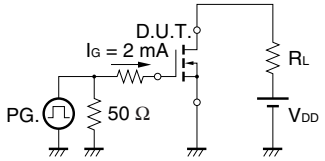
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

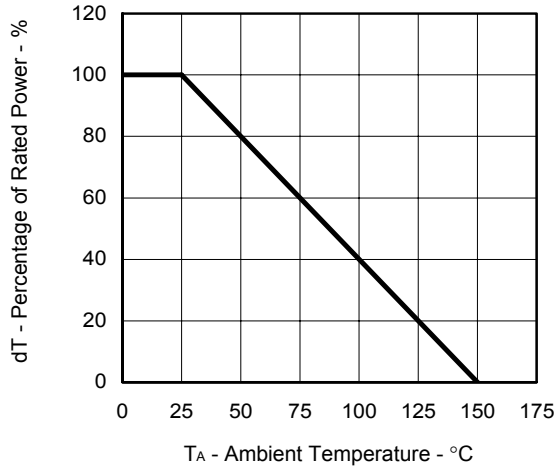


TEST CIRCUIT 3 GATE CHARGE

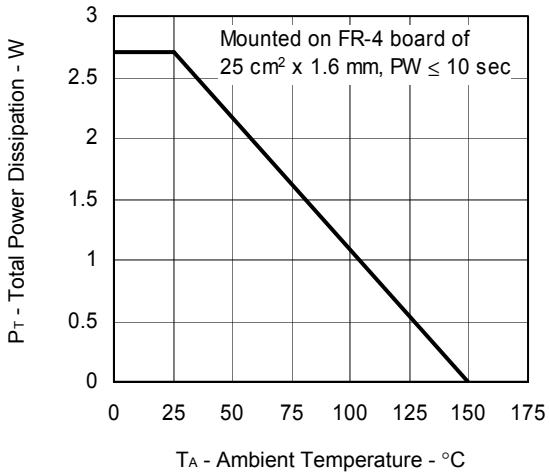


TYPICAL CHARACTERISTICS (T_A = 25°C)

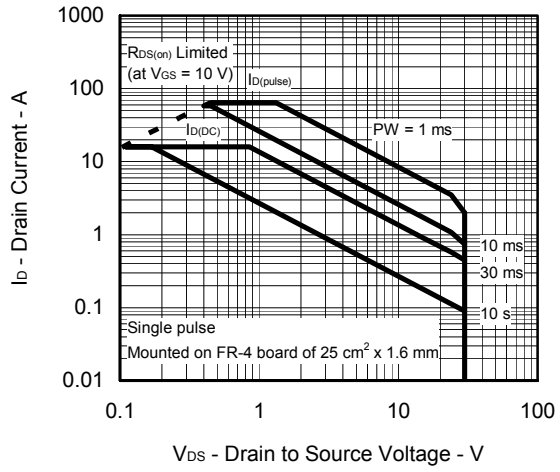
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



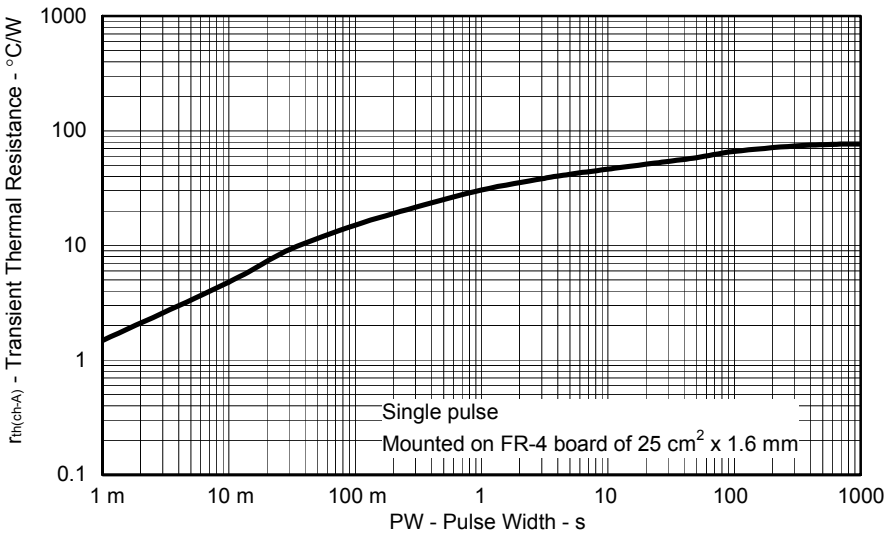
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



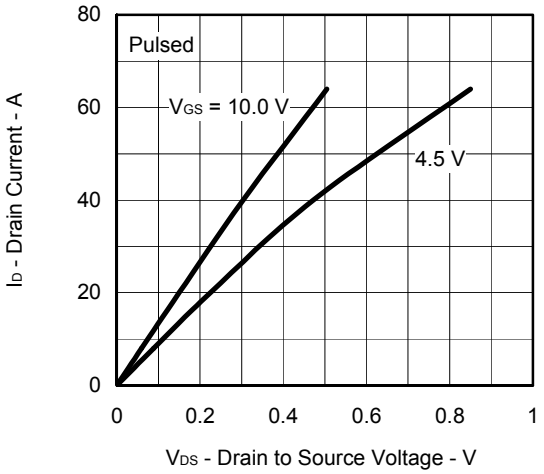
FORWARD BIAS SAFE OPERATING AREA



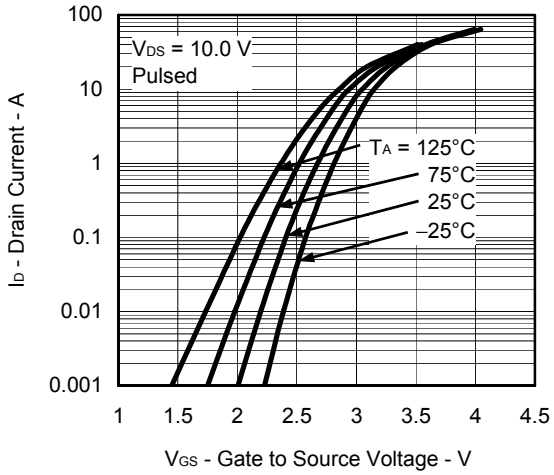
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



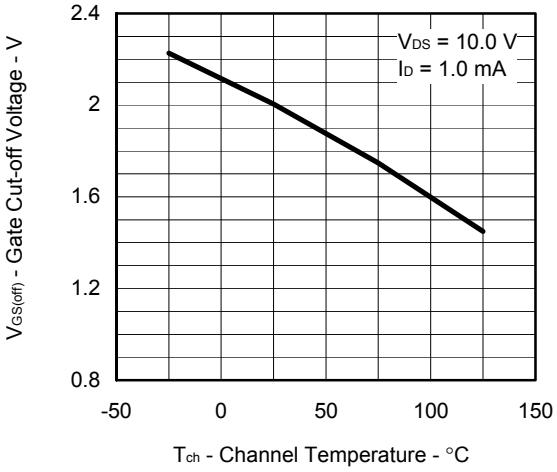
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



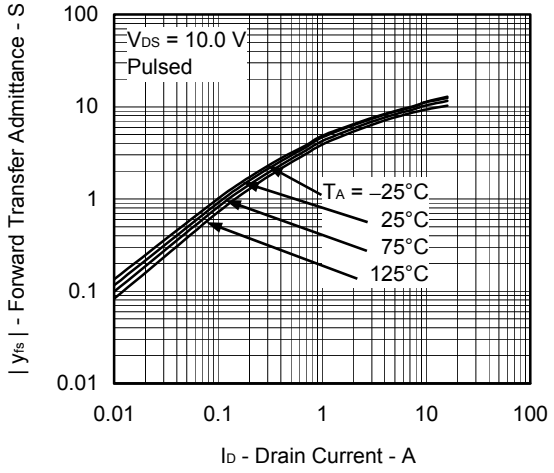
FORWARD TRANSFER CHARACTERISTICS



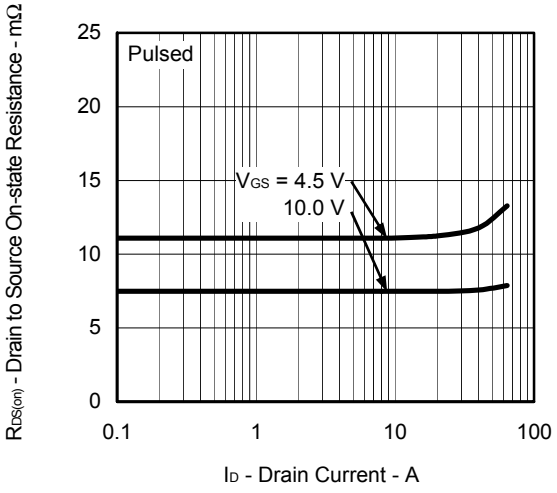
GATE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



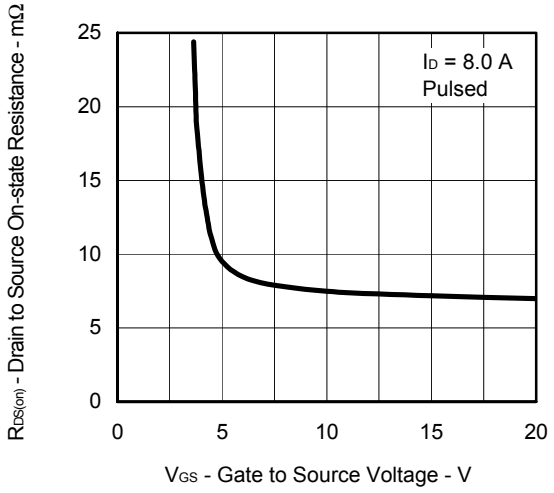
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



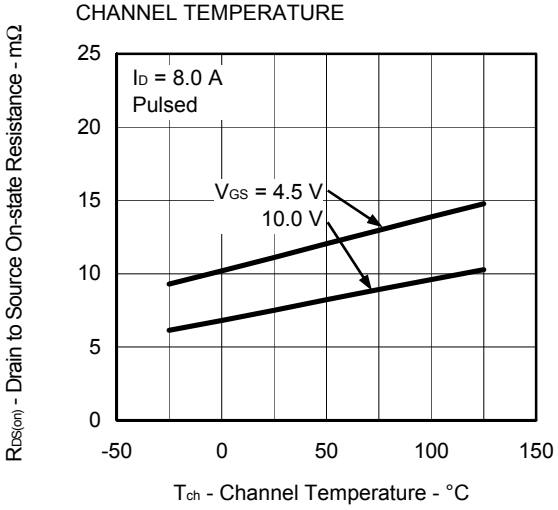
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



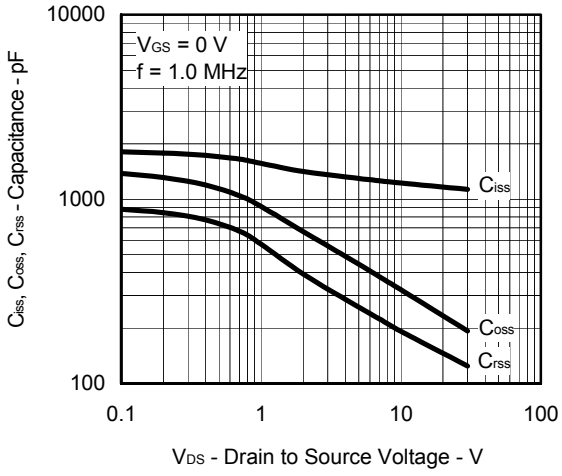
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



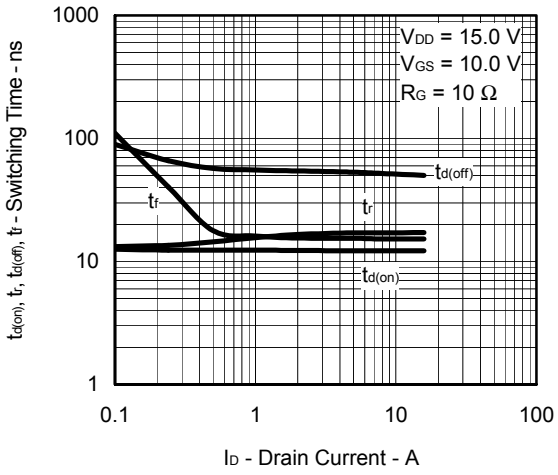
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



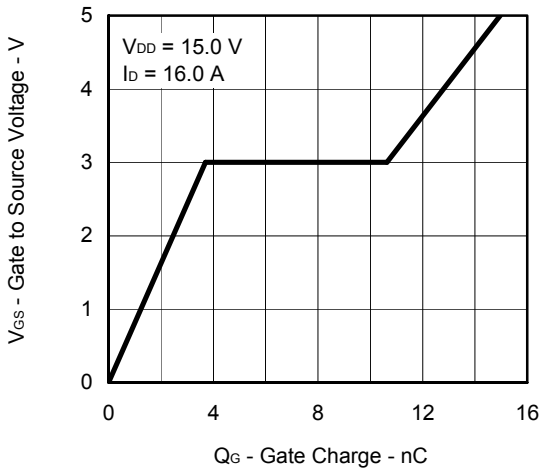
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



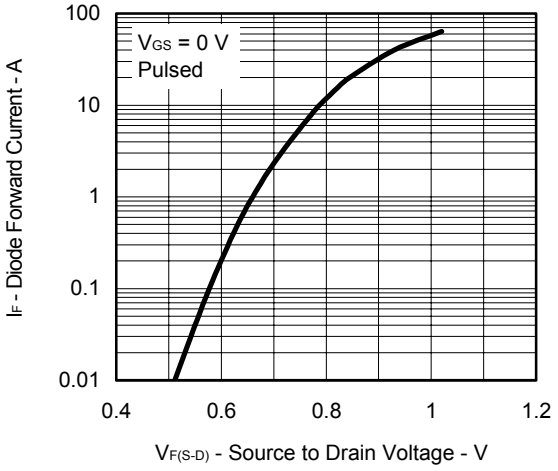
SWITCHING CHARACTERISTICS



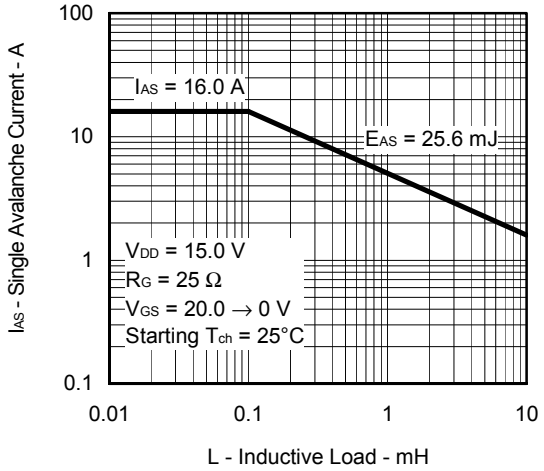
DYNAMIC INPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

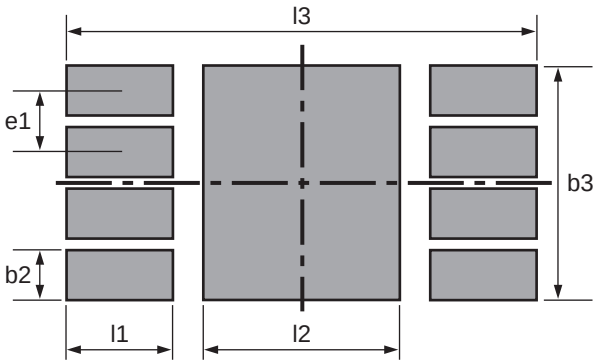


SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



EXAMPLE OF THE LAND PATTERN

Please optimize the land pattern in consideration of density, appearance of solder fillets, common difference, etc in an actual design.



e1: 0.65
b2: 0.35
b3: 2.7
l1: 1.3
l2: 3.7
l3: 7.1

(Unit: mm)

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